Dof	Llita	Soarch Quant	DPs	Dofessile	Dhamala	Time Ctarre
Ref # 	Hits	Search Query	DBs .	Default Operator	Plurals	Time Stamp
L2	1	(US-6225656-\$).did.	USPAT	OR	OFF	2007/11/29 16:06
L3	1	2 and nonconductive adj3 barrier	USPAT	OR	ON	2007/11/29 16:10
L4	1	3 and nitride and oxide and glass	USPAT	OR	ON	2007/11/29 16:11
L5	0	3 and nitride and oxide and glass and nitrogen and oxygen	USPAT	OR	ON	2007/11/29 16:11
L6	1	3 and nitride and oxide and glass and oxygen	USPAT	OR	ON	2007/11/29 16:11
L11	138	carbon with content with insulating adj film	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/11/29 17:05
L12	41	11 and capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/11/29 17:11
L13	97	11 not 12	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/11/29 17:15
L14	2	("2002203899").PN.	JPO; DERWENT	OR	OFF	2007/11/29 17:17
L15	45	MITSUSHIMA and adhesi\$7	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 17:17
L16	1	MITSUSHIMA and adhesi\$7 with carbon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 17:17

L17	7	MITSUSHIMA and adhesi\$7 and carbon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 17:19
L18	119	ohto and adhesi\$7 and carbon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 17:19
L19	63	(usami ohto) and adhesi\$7 with carbon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 17:24
L20	4	"6784485"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR ·	OFF	2007/11/29 17:27
L21	3	20 and barrier and hydrogen	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 17:28
L22	4	20 and barrier and diffusion	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 17:31
L23	1	20 and percent	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 17:31

L24	142	RI.IN. AND CAPACITOR	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L25	2677	silicon adj (oxide dioxide) with dielectric with carbon	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2007/11/29 18:36
L26	640	L25 and teos	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR .	ON	2007/11/29 18:36
L27	12003	((257/295-306) or (361/302-305, 310-313)).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/11/29 18:36
L28	433	L27 and (silane or carbon) with (insulating insulation insulated dielectric)	US-PGPUB; USPAT	OR	ON	2007/11/29 18:36
L29	26	second capacitor protection	US-PGPUB; USPAT	ADJ	OFF .	2007/11/29 18:36
L30	29743	carbon and capacitor	US-PGPUB; USPAT	OR	OFF	2007/11/29 18:36
L31	104	"5,554,570"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR ·	OFF	2007/11/29 18:36
L32	6	(("20020006674") or ("6570203") or ("6171970")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L33	6	Sashida and carbon and capacitor not ("10315929" "315929")	US-PGPUB; USPAT	OR	OFF	2007/11/29 18:36
L34	352	SAMSUNG AND BLOCKING AND HYDROGEN	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L35	741	(low-k or low dielectric constant) with carbon with silicon (dioxide or oxide) and barrier	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L36	9	Sashida and carbon and capacitor	US-PGPUB; USPAT	OR	OFF	2007/11/29 18:36

L37	4280	(chemical vapor deposition or CVD) and bias voltage and carbon	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L38	560	ferroelectric capacitor and (barrier adj dielectric or diffusion adj barrier)	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L39	35	"6509601"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L40	15	RI.IN. AND CAPACITOR AND FERROELECTRIC	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L41	3	(("20020006674") or ("6570203") or ("6171970")).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/11/29 18:36
L42	2	(US-20040089894-\$ or US-20030178663-\$).did. or (US-6673672-\$).did.	US-PGPUB; USPAT	OR	OFF	2007/11/29 18:36
L43	265	(chemical vapor deposition or CVD) and bias voltage and carbon content	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L44	265	carbon and L43	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L45	984	(low-k or low dielectric constant) with carbon with silicon (dioxide or oxide)	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L46		L42 and (carbon plasma cvd pecvd lpcvd) with second adj (capacitor insulating)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L47	98	L31 and (silane or carbon)	US-PGPUB; USPAT	OR	ON	2007/11/29 18:36
L48	6	("1077483").PN.	EPO; DERWENT	OR	OFF	2007/11/29 18:36
L49	.21	"5,554,559"	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L50	339	RI AND FERROELECTRIC	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR .	OFF	2007/11/29 18:36
L51	426	RI.IN.	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36

L52	104	"5,554,570"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L53	86	L52 and (silane or carbon) with plasma	US-PGPUB; USPAT	OR	ON	2007/11/29 18:36
L54	2	("6121648" "6249014" "6426255" "66 90055").PN. and hydrogen adj barrier	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L55	59	carbon same teos same silane and carbon near (content composition concentratation)	US-PGPUB; USPAT	OR	ON	2007/11/29 18:36
L56	558	L26 and plasma	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2007/11/29 18:36
L57	3	L41 and (carbon plasma cvd pecvd lpcvd)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L58 .	17	ferroelectric capacitor and (barrier adj dielectric or diffusion adj barrier near dielectric)	US-PGPUB; USPAT	ADJ .	OFF	2007/11/29 18:36
L59	40	L56 and plasma with teos and cvd with ozone with teos	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2007/11/29 18:36
L60	31	ABDELGADIR	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L61	. 15	SAMSUNG AND BLOCKING AND HYDROGEN AND FERROELECTRIC	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L62	16	Sashida and carbon and insulating adj film	US-PGPUB; USPAT	OR	OFF	2007/11/29 18:36
L63	2085	(257/306).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/11/29 18:36
L64	1644	L27 and (silane or carbon)	US-PGPUB; USPAT	OR	ON	2007/11/29 18:36

L65	3	(US-5275977-\$ or US-6201271-\$ or US-5554570-\$).did.	USPAT	OR	OFF	2007/11/29 18:36
L66	18	"5,554,559" and hydrogen	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L67	174	dielectric and L43	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L68	301	L25 and carbon adj content	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2007/11/29 18:36
L69	4	(low-k or low dielectric constant) with carbon with silicon (dioxide or oxide)and pzt	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L70	12	plate adj capacitor and fourth adj interlayer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/11/29 18:36
L71	61	dielectric adj constant with carbon content with oxide	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L72	56	(chemical vapor deposition or CVD) and bias voltage and carbon content with oxide	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L73	402	carbon same teos same silane	US-PGPUB; USPAT	OR	ON	2007/11/29 18:36
L74	518	(low-k or low dielectric constant) with carbon near2 silicon (dioxide or oxide)	US-PGPUB; USPAT	ADJ	OFF	2007/11/29 18:36
L75	607	capacitor and fourth adj interlayer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2007/11/29 18:36
L76		(10/315929 "10315929" "315929") and sashida	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36

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L77	1	L36 and (plug and hole).clm.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L78	,0	L36 and (protective and hole).clm.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L79	5	L36 and (hole).clm.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:36
L80	8	("5475248"   "5481490"   "5510651"   "5780351"   "6184927"   "6200821"   "6355952"   "6495879").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/11/29 18:36
L81	6	(Hikosaka near2 Yukinobu Ozaki near2 Yasutaka Takai near2 Kazuaki).in. and ferroelectric and @pd<"20030101"	US-PGPUB; USPAT; USOCR	OR	OFF	2007/11/29 18:36
L82	0	jp-06290984-\$	US-PGPUB; USPAT; USOCR	OR	OFF	2007/11/29 18:36
L83	2	jp-06290984-\$	JPO; DERWENT	OR	OFF	2007/11/29 18:36
L84	. 4	("5693553"   "6204111"   "6204203"   "6346424").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/11/29 18:36
L85	32	second capacitor protection	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF .	2007/11/29 18:36
L86	7	L36 and plug and hole	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/11/29 18:49